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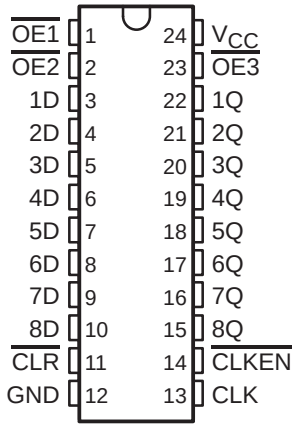
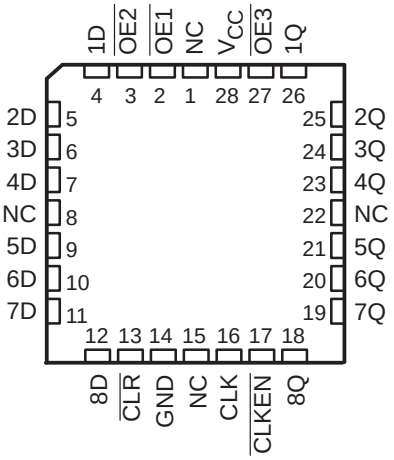
- **Functionally Equivalent to AMD's AM29825**
- **Improved I_{OH} Specifications**
- **Multiple Output Enables Allow Multiuser Control of the Interface**
- **Outputs Have Undershoot-Protection Circuitry**
- **Power-Up High-Impedance State**
- **Buffered Control Inputs Reduce dc Loading Effects**
- **Package Options Include Plastic Small-Outline (DW) Packages, Ceramic Chip Carriers (FK), and Standard Plastic (NT) and Ceramic (JT) 300-mil DIPs**

SN54AS825A . . . JT PACKAGE
SN74AS825A . . . DW OR NT PACKAGE
(TOP VIEW)



SN54AS825A . . . FK PACKAGE
(TOP VIEW)



NC – No internal connection

description

These 8-bit flip-flops feature 3-state outputs designed specifically for driving highly capacitive or relatively low-impedance loads. These devices are particularly suitable for implementing multiuser registers, I/O ports, bidirectional bus drivers, and working registers.

With the clock-enable ($\overline{CLKEN}$) input low, the eight D-type edge-triggered flip-flops enter data on the low-to-high transitions of the clock (CLK) input. Taking $\overline{CLKEN}$ high disables the clock buffer, latching the outputs. These devices have noninverting data (D) inputs. Taking the clear ($\overline{CLR}$) input low causes the eight Q outputs to go low independently of the clock.

Multiuser buffered output-enable ($\overline{OE1}$, $\overline{OE2}$, and $\overline{OE3}$) inputs can be used to place the eight outputs in either a normal logic state (high or low logic level) or a high-impedance state. In the high-impedance state, the outputs neither load nor drive the bus lines significantly. The high-impedance state and increased drive provide the capability to drive bus lines without interface or pullup components.

The output enables do not affect the internal operation of the flip-flops. Old data can be retained or new data can be entered while the outputs are in the high-impedance state.

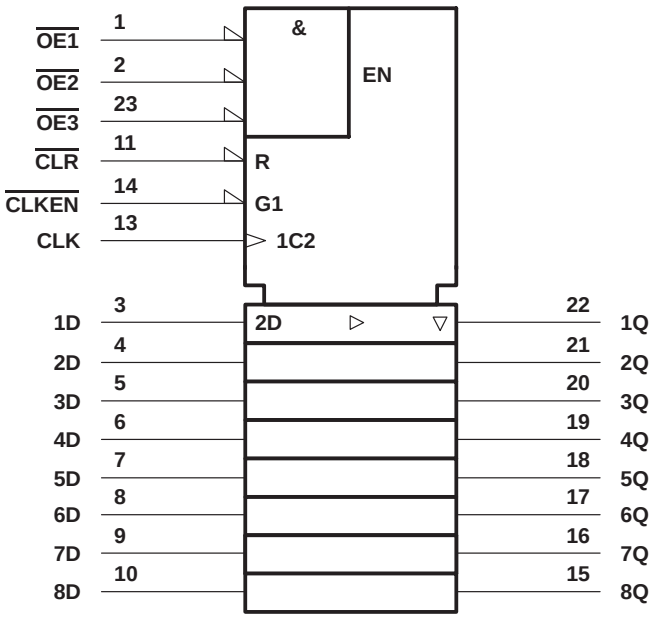
The SN54AS825A is characterized for operation over the full military temperature range of –55°C to 125°C. The SN74AS825A is characterized for operation from 0°C to 70°C.

FUNCTION TABLE
(each flip-flop)

INPUTS					OUTPUT
$\overline{OE}$†	$\overline{CLR}$	$\overline{CLKEN}$	CLK	D	Q
L	L	X	X	X	L
L	H	L	↑	H	H
L	H	L	↑	L	L
L	H	H	X	X	Q_0
H	X	X	X	X	Z

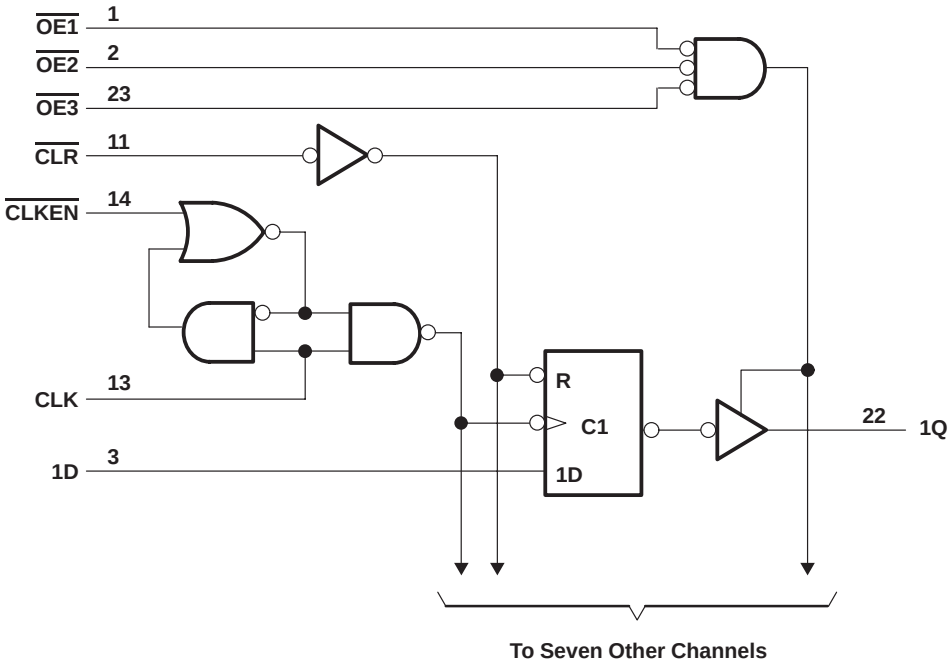
† $\overline{OE}$ = H if any of $\overline{OE1}$, $\overline{OE2}$, or $\overline{OE3}$ are high.
$\overline{OE}$ = L if all of $\overline{OE1}$, $\overline{OE2}$, or $\overline{OE3}$ are low.

logic symbol‡



‡ This symbol is in accordance with ANSI/IEEE Std 91-1984 and IEC Publication 617-12.
Pin numbers shown are for the DW, JT, and NT packages.

logic diagram (positive logic)



Pin numbers shown are for the DW, JT, and NT packages.

absolute maximum ratings over operating free-air temperature range (unless otherwise noted)†

Supply voltage, V_{CC} . . . . . 7 V
Input voltage, V_I . . . . . 7 V
Voltage applied to a disabled 3-state output . . . . . 5.5 V
Operating free-air temperature range, T_A: SN54AS825A . . . . . –55°C to 125°C
SN74AS825A . . . . . 0°C to 70°C
Storage temperature range . . . . . –65°C to 150°C

† Stresses beyond those listed under “absolute maximum ratings” may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under “recommended operating conditions” is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

recommended operating conditions

			SN54AS825A			SN74AS825A			UNIT
			MIN	NOM	MAX	MIN	NOM	MAX	
V_{CC}	Supply voltage		4.5	5	5.5	4.5	5	5.5	V
V_{IH}	High-level input voltage		2			2			V
V_{IL}	Low-level input voltage				0.7			0.8	V
I_{OH}	High-level output current				–24			–24	mA
I_{OL}	Low-level output current				32			48	mA
t_w*	Pulse duration	$\overline{CLR}$ low	7			4			ns
		CLK high or low	9.5			8			
t_{su}*	Setup time before CLK↑	$\overline{CLR}$ inactive	8			8			ns
		Data	7			6			
		$\overline{CLKEN}$ high or low	10			6			
t_h*	Hold time after CLK↑	$\overline{CLKEN}$ low or data	0			0			ns
T_A	Operating free-air temperature		–55		125	0		70	°C

* On products compliant to MIL-STD-883, Class B, this parameter is based on characterization data but is not production tested.

electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER	TEST CONDITIONS		SN54AS825A			SN74AS825A			UNIT
			MIN	TYP†	MAX	MIN	TYP†	MAX	
V_{IK}	V_{CC} = 4.5 V,	I_I = –18 mA			–1.2			–1.2	V
V_{OH}	V_{CC} = 4.5 V to 5.5 V,	I_{OH} = –2 mA	V_{CC} –2			V_{CC} –2			V
	V_{CC} = 4.5 V	I_{OH} = –15 mA	2.4	3.2		2.4	3.2		
		I_{OH} = –24 mA	2			2			
V_{OL}	V_{CC} = 4.5 V	I_{OL} = 32 mA		0.3	0.5				V
		I_{OL} = 48 mA					0.35	0.5	
I_{OZH}	V_{CC} = 5.5 V,	V_O = 2.7 V			50			50	µA
I_{OZL}	V_{CC} = 5.5 V,	V_I = 0.4 V			–50			–50	µA
I_I	V_{CC} = 5.5 V,	V_I = 7 V			0.1			0.1	mA
I_{IH}	V_{CC} = 5.5 V,	V_I = 2.7 V			20			20	µA
I_{IL}	V_{CC} = 5.5 V,	V_I = 0.4 V			–0.5			–0.5	mA
I_O‡	V_{CC} = 5.5 V,	V_O = 2.25 V	–30		–112	–30		–112	mA
I_{CC}	V_{CC} = 5.5 V	Outputs high		45	73		45	73	mA
		Outputs low		56	90		56	90	
		Outputs disabled		59	95		59	95	

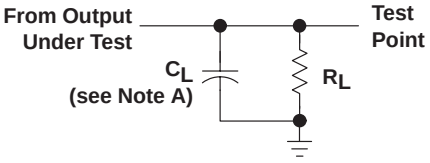
† All typical values are at V_{CC} = 5 V, T_A = 25°C.
‡ The output conditions have been chosen to produce a current that closely approximates one half of the true short-circuit output current, I_{OS}.

switching characteristics (see Figure 1)

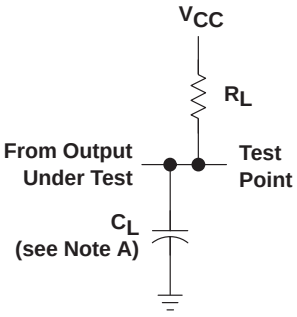
PARAMETER	FROM (INPUT)	TO (OUTPUT)	V_{CC} = 4.5 V to 5.5 V, C_L = 50 pF, R1 = 500 Ω, R2 = 500 Ω, T_A = MIN to MAX†				UNIT
			SN54AS825A		SN74AS825A		
			MIN	MAX	MIN	MAX	
t_{PLH}	CLK	Any Q	3.5	9	3.5	7.5	ns
t_{PHL}			3.5	13.5	3.5	13	
t_{PHL}	$\overline{CLR}$	Any Q	3.5	16.5	3.5	15.5	ns
t_{PZH}	$\overline{OE}$	Any Q	4	12	4	11	ns
t_{PZL}			4	13	4	12	
t_{PHZ}	$\overline{OE}$	Any Q	1	10	1.5	8	ns
t_{PLZ}			1	10	1.5	8	

† For conditions shown as MIN or MAX, use the appropriate value specified under recommended operating conditions.

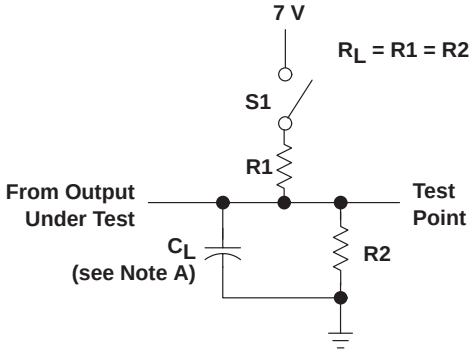
PARAMETER MEASUREMENT INFORMATION
SERIES 54ALS/74ALS AND 54AS/74AS DEVICES



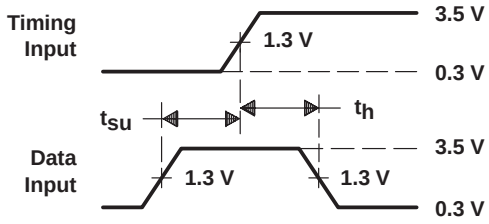
LOAD CIRCUIT FOR
BI-STATE
TOTEM-POLE OUTPUTS



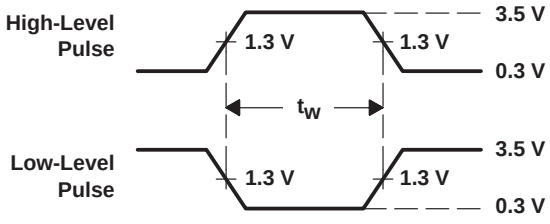
LOAD CIRCUIT
FOR OPEN-COLLECTOR OUTPUTS



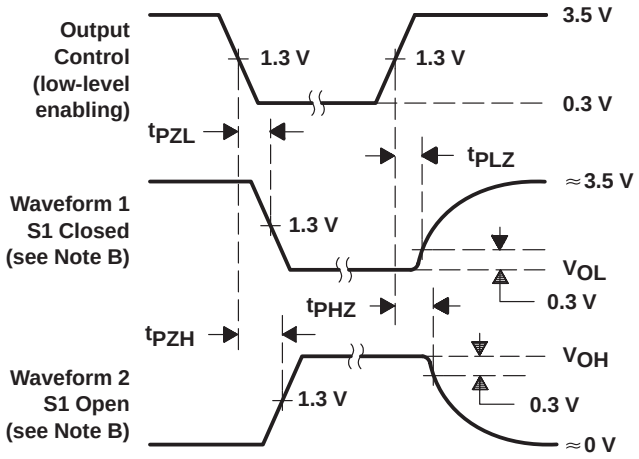
LOAD CIRCUIT
FOR 3-STATE OUTPUTS



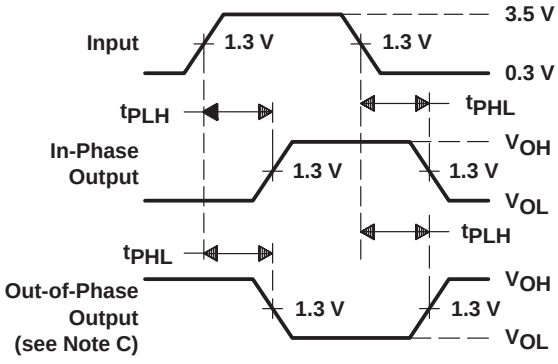
VOLTAGE WAVEFORMS
SETUP AND HOLD TIMES



VOLTAGE WAVEFORMS
PULSE DURATIONS



VOLTAGE WAVEFORMS
ENABLE AND DISABLE TIMES, 3-STATE OUTPUTS



VOLTAGE WAVEFORMS
PROPAGATION DELAY TIMES

NOTES: A. C_L includes probe and jig capacitance.
B. Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high except when disabled by the output control.
C. When measuring propagation delay items of 3-state outputs, switch S1 is open.
D. All input pulses have the following characteristics: PRR ≤ 1 MHz, $t_r = t_f = 2$ ns, duty cycle = 50%.
E. The outputs are measured one at a time with one transition per measurement.

Figure 1. Load Circuits and Voltage Waveforms

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